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Kind regards,

Team Nexperia

PDTC123T series

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = open Rev. 01 — 10 March 2006 Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistors (RET) family in Surface Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package	Package			
	Philips	JEITA	JEDEC		
PDTC123TE	SOT416	SC-75	-	PDTA123TE	
PDTC123TK	SOT346	SC-59A	TO-236	PDTA123TK	
PDTC123TM	SOT883	SC-101	-	PDTA123TM	
PDTC123TS[1]	SOT54	SC-43A	TO-92	PDTA123TS	
PDTC123TT	SOT23	-	TO-236AB	PDTA123TT	
PDTC123TU	SOT323	SC-70	-	PDTA123TU	

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Control of IC inputs

- Cost-saving alternative for BC847 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
I _O	output current		-	-	100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ



2. Pinning information

Table 3. **Pinning** Pin Description Simplified outline **Symbol** SOT54 1 input (base) output (collector) 3 GND (emitter) 001aab347 006aaa218 SOT54A 1 input (base) 2 output (collector) 3 GND (emitter) R1 001aab348 006aaa218 **SOT54** variant input (base) 2 output (collector) 3 GND (emitter) 001aab447 006aaa218 SOT23; SOT323; SOT346; SOT416 input (base) 3 2 GND (emitter) 3 output (collector) 2 006aaa144 sym012 **SOT883** 1 input (base) 2 GND (emitter) 3 output (collector) Transparent top view

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PDTC123TE	SC-75	plastic surface mounted package; 3 leads	SOT416
PDTC123TK	SC-59A	plastic surface mounted package; 3 leads	SOT346
PDTC123TM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883
PDTC123TS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54
PDTC123TT	-	plastic surface mounted package; 3 leads	SOT23
PDTC123TU	SC-70	plastic surface mounted package; 3 leads	SOT323

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5. Marking codes

Tunio di Indiana di Granda	
Type number	Marking code ^[1]
PDTC123TE	2B
PDTC123TK	GB
PDTC123TM	FB
PDTC123TS	TC123T
PDTC123TT	ZM*
PDTC123TU	*1T

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
Io	output current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	SOT416		<u>[1]</u> _	150	mW
	SOT346		<u>[1]</u> _	250	mW
	SOT883		[2][3]	250	mW
	SOT54		<u>[1]</u> -	500	mW
	SOT23		<u>[1]</u> -	250	mW
	SOT323		<u>[1]</u> -	200	mW
T _{stg}	storage temperature		–65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

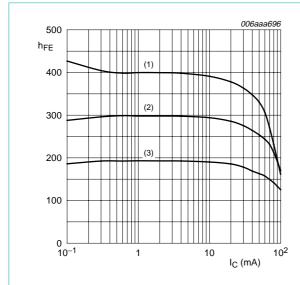
^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

7. Characteristics

Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

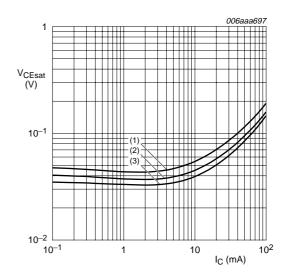
G	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I_{CEO}	collector-emitter cut-off	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
	current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 5 V; I_{C} = 20 mA	30	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	150	mV
R1	bias resistor 1 (input)		1.54	2.2	2.86	$k\Omega$
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF





- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \,^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values

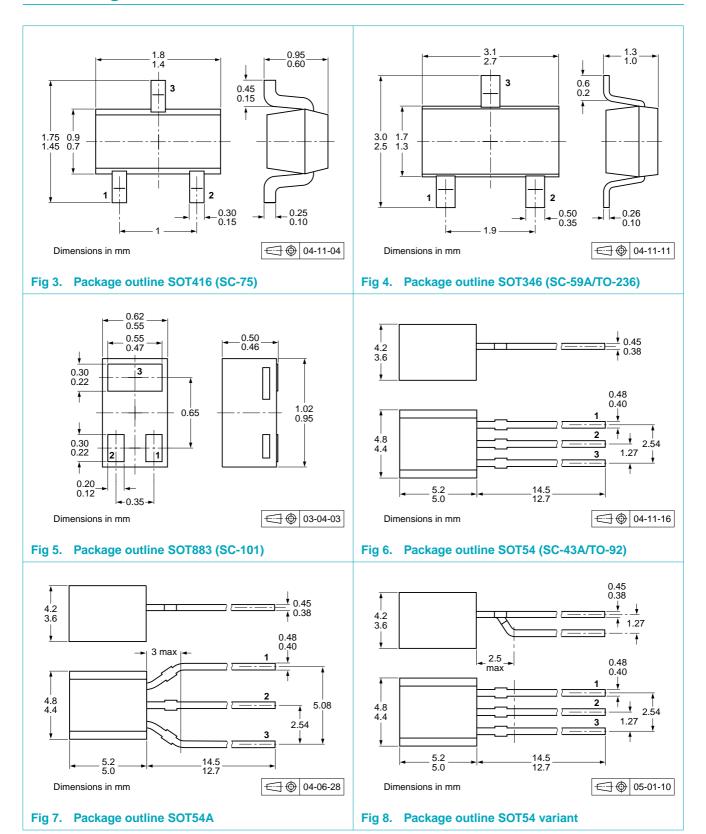


$$I_{\rm C}/I_{\rm B} = 20$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

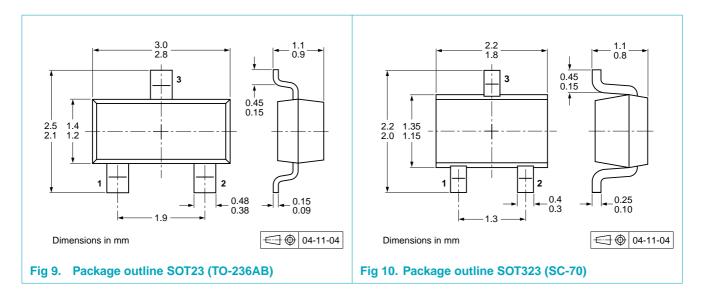
Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

8. Package outline



PDTC123T_SER_1

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9. Packing information

Table 9. Packing methods
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packin	Packing quantity			
			3000	5000	10000		
PDTC123TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTC123TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTC123TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315		
PDTC123TS	SOT54	bulk, straight leads	-	-412	-		
	SOT54A	tape and reel, wide pitch	-	-	-116		
		tape ammopack, wide pitch	-	-	-126		
	SOT54 variant	bulk, delta pinning	-	-112	-		
PDTC123TT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235		
PDTC123TU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135		

^[1] For further information and the availability of packing methods, see Section 12.

PDTC123T series

NPN resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC123T_SER_1	20060310	Product data sheet	-	-

Product data sheet

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTC123T series

NPN resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

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